

OPTEK Optimal Series Thermal Resistance



Application Bulletin 238

This application bulletin is written to show how Thermal Resistance is calculated for the OPTEK Optimal series devices.

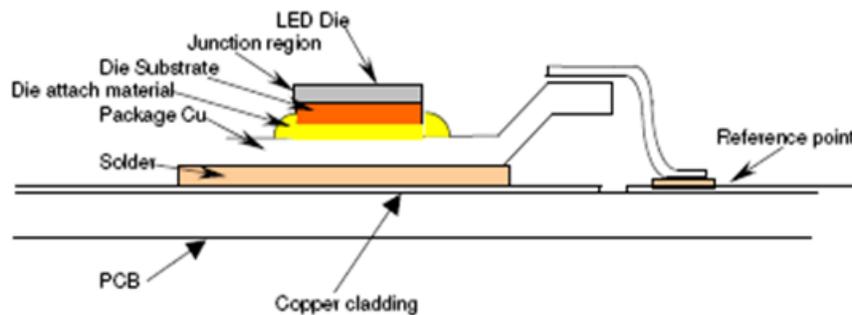
Optek Lednium Series 1-watt Cup – Measured value 2oC/w (OVTL01LGxx)

Optek Lednium Series 10-watt Matrix – Measured value 2.5oC/w (OVTL09LG3xx)

Theory

In line with industry practice, the thermal resistance (R_{th}) of our LED packages is stated as R_{qj-b} , thermal resistance from the junction region (j) of the die, to the board (b) - PCB or other mounting surface. What this means in a practical sense, is that when operating at rated input (1watt approx.) the junction of a die in a cup product will attain a temperature that is 2oC higher than a reference point on the mounting surface beneath it. In the case of a 10-watt Matrix product, the maximum temperature difference between any junction and the reference point is 25oC (2.5oC/w x 10w). The thermal path thus quantified is a composite of a number of thermally resistive elements in a series and or parallel configuration, but lumped together into a single parameter for convenience.

For an end user of LED products then, this constant allows the junction temperature to be determined by a simple measurement of the temperature of the mounting surface. Optek recommends that the design value of sustained die junction temperature be limited to 80oC. In an ambient temperature of 25oC, the board temperature of a 10-watt device must be constrained below 55oC to comply with this recommendation, and for a 1-watt cup the board can theoretically operate at up to 78oC.



From the diagram above it can be seen that the heat generated in the junction region follows a somewhat serial conductive path through the package to the major radiating surface – which in this example is a single sided PCB. Some additional radiation may occur directly from the upper surface of the package (not shown). This would be conducted upward from the die surface through the transparent encapsulating material to the package surface and be radiated from there. To all practical purposes this is a very minor effect. The polymer encapsulants in normal use are poor conductors of heat.

General Note

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Typical elements in the conducting path and corresponding nominal thermal conductivities are:

	Elements	w/mK
Epilayers	GaN/InGaN	150
Substrate	Sapphire	50
Die attach material	Conductive epoxy	10
Package	Silver plated copper	350
Solder	Solder (Sn/Ag/Cu)	35
Copper cladding	Copper	300

Note : Thermal conductivity is a physical constant. For the materials above, the respective contribution each makes to the overall thermal resistance (Rq j-b) is a function of the thickness of each material layer, and the surface area. Thermal Conductivity (TC) is defined to be the heat conducted in time (t), through thickness (T) in a direction normal to a surface area (A), due to a temperature difference (dT).

Therefore $TC = q/t \times \{T/[A \times \delta T]\}$

and $\delta T = [Q \times T]/[A \times TC]$ where $\delta T =$ Temp. difference (K)
 $Q =$ Power (w)
 $A =$ Surface area (m²)
 $T =$ layer thickness (m)
 $TC =$ Thermal Conductivity (w/mK)

Theoretical Calculation (for 1 watt dissipated in a cup product via a single 40mil die)

GaN	Thickness approx 10×10^{-6} Area 10^{-6}	$= 1 \times 10 \times 10^{-6} / 10^{-6} \times 150$ $= 0.07 \text{ K}$
Substrate	$T = 60 \times 10^{-6}$	$= 1 \times 60 \times 10^{-6} / 10^{-6} \times 50$ $= 1.2 \text{ K}$
Die attach	$T = 20 \times 10^{-6}$ $A = 2 \times 10^{-6}$	$= 1 \times 20 \times 10^{-6} / 2 \times 10^{-6} \times 10$ $= 1$
Package	$T = 0.4 \times 10^{-3}$ $A = 6 \times 10^{-6}$	$= 1 \times 0.4 \times 10^{-3} / 6 \times 10^{-6} \times 350$ $= 0.19$
Solder	$T = 60 \times 10^{-6}$ $A = 6 \times 10^{-6}$	$= 1 \times 60 \times 10^{-6} / 6 \times 10^{-6} \times 25$ $= 0.4$

Total Calculated $\delta T = 2.86 \text{ K}$

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Power input is 1 watt; however, some power is converted into light energy. Assuming this is of the order of 200mw, the adjusted value of dT is 2.29K. The calculation now assumes that all of the dissipation, 800mw of heat, is conducted along the thermal path, thereby ignoring any conduction and subsequent radiation that is not directionally normal to the surfaces considered, ie: conduction through the encapsulant material vertically away from the board, and conduction horizontally away from the heat source. The calculation also assumes that there is no contribution to thermal resistance at the boundaries between material layers. In practice it is improbable that perfect transfer will occur at these transition regions, even though the bonding between layers in this example are of high quality. In general, the calculation indicates that the measurements below are of the order of magnitude that can be expected.

The alternate matrix product range is of a much more complicated thermal design, which does not lend itself to a simple theoretical calculation similar to that shown above. There are multiple incident heat sources, parallel heat conduction paths, and significantly larger surface area for stray radiation, eg. Cup above has a surface area available for stray radiation of approximately, 25mm² per watt of input power. A 10-watt matrix product has approximately 92.5mm² of exposed surface per input watt.

Measurements

The key to an accurate measurement of thermal resistance is to obtain a reliable value for the junction temperature (T_j). Since the die itself is, and must be, encapsulated during testing, and the junction is contained within the structure of the die, direct measurement of the junction temperature by normal means is not possible. Two methods of non-contact thermography are available, both of which rely on emitted infrared detection.

Infrared imagery by calibrated radiograph is a possibility; however, in the instance of a cup product only a small value of dT is expected which makes accurate estimation of the actual temperature gradient difficult using colorimetry.

The alternative measurement type is digital infrared thermography. This means there is an inherent uncertainty in the calculation algorithm, which sometimes gives results considered unacceptably inaccurate. In this instance absolute accuracy is of secondary importance because the value to be determined is a temperature difference (dT) which requires only relative values – any error in a first reading will also be present in subsequent readings that are about the same value. The difference between readings is accurate.

The other significant drawback to infrared thermometers is a limitation to minimizing the spot size over which the measurement is made. This poses a difficulty for small assemblies like an LED cup, and in particular the added complication that the calculated temperature is an average value for the area being interrogated further complicates the issue. Another concern is sometimes raised about the ability of this type of instrument to detect a heated surface beyond the closest transparent radiating surface. This is a significant issue for far field measurements; however, it is simple to demonstrate that this does not hold true for the near field, and particularly when the incident beam has a known focal length.

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Application Title

Application Bulletin



Measurement

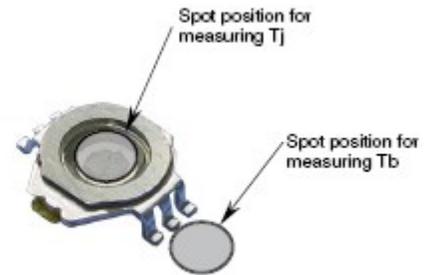
Instrument: IR Thermometer
Auto ranging: -100 to 1200°C
Spot size 3mm D.
Focus 25.4mm

Cup Product

Input 350mA at 3.3V(1watt)



Device under test



Averaged Test Results

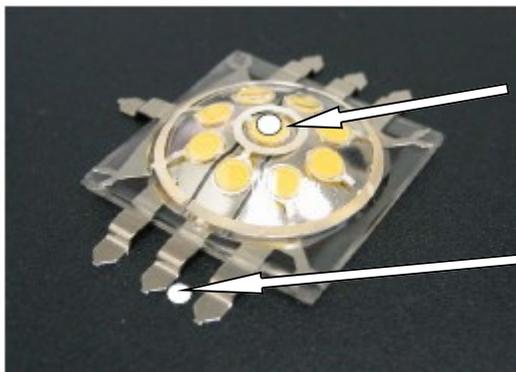
T_j	T_b	δT	Rth
32	30.2	1.8	1.8°C/W

Matrix Product

Input 1050mA at 10.2V(10.7watts)

Averaged Test Results

T_j	T_b	δT	Rth
89	62	27	2.52°C/W



Measurement points



Test set-up on MCPCB

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